



Features

- Flexible driving strategy via configurable pins PWM/DIR (IN1/IN2)
- $R_{DSon} < 400 \text{ m}\Omega$ (full path at $T_j = 150^\circ \text{C}$)
- Operating battery supply voltage from 4.5 V up to 28 V
- Operating VDD5 supply voltage from 4.5 V to 5.5 V
- Input switching frequency up to 20 kHz
- Built in charge pump supporting 100% duty cycle
- Logic levels compatible to 3.3 V and 5 V
- Monitoring of VDD5 supply voltage with bidirectional switch-off pin
- Current limitation SPI-adjustable in four steps.
- Output stage current limitation with dependence on temperature

- 2 Programmable voltage and current slew rate control
- Short circuit and programmable thermal warning and shutdown thresholds
- Open Load diagnosis in ON condition
- All I/O pins can withstand up to 19 V
- SPI interface for configuration and diagnosis
- Two independent enable/disable pins NDIS and DIS and SOPC (Switch-off Path Check) available
- Spread Spectrum function for EMI reduction
- Available in single (L9960) and Twin (L9960T) option, both in PSSO36 package

Description

The device is an integrated H-Bridge for resistive and inductive loads for automotive applications, such as throttle control actuators or exhaust gas recirculation control valves.

The driving strategy is enhanced by configurable PWM / DIR pins and IN1/IN2.

The H-Bridge contains integrated free-wheel diodes. In case of freewheeling condition, the low side only is switched on in parallel of its diode to reduce power dissipation.

The integrated Serial Peripheral Interface (SPI) makes it possible to adjust device parameters, to control all operating modes and read out diagnostic information.

Table 1. Device summary

Order code	Package	Packing
L9960	PowerSSO-36	Tube
L9960TR		Tape and Reel
L9960T		Tube
L9960T-TR		Tape and Reel

Contents

- 1 Block diagram and pin description 3**
 - 1.1 Block diagram 3
 - 1.2 Pin description 4
 - 1.2.1 PowerSSO36 package 4

- 2 Application description 7**
 - 2.1 Functionality 7
 - 2.2 Example of application circuit 8

- 3 General electrical characteristics 10**
 - 3.1 Absolute maximum ratings 10

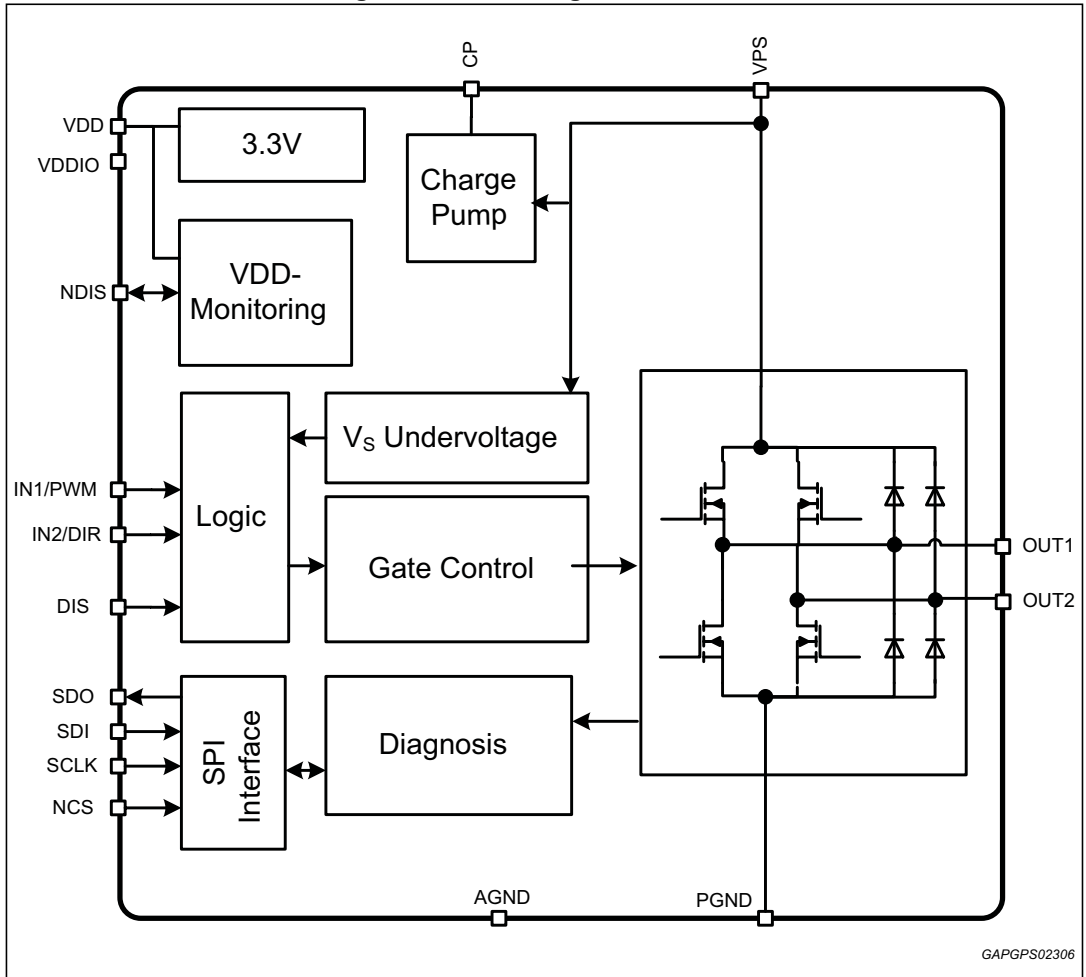
- 4 Package information 11**
 - 4.1 PowerSSO-36 (exposed pad) package mechanical data 11

- 5 Revision history 14**

1 Block diagram and pin description

1.1 Block diagram

Figure 1. Block diagram for L9960



1.2 Pin description

1.2.1 PowerSSO36 package

Figure 2. Pin connection of L9960 version (top view)

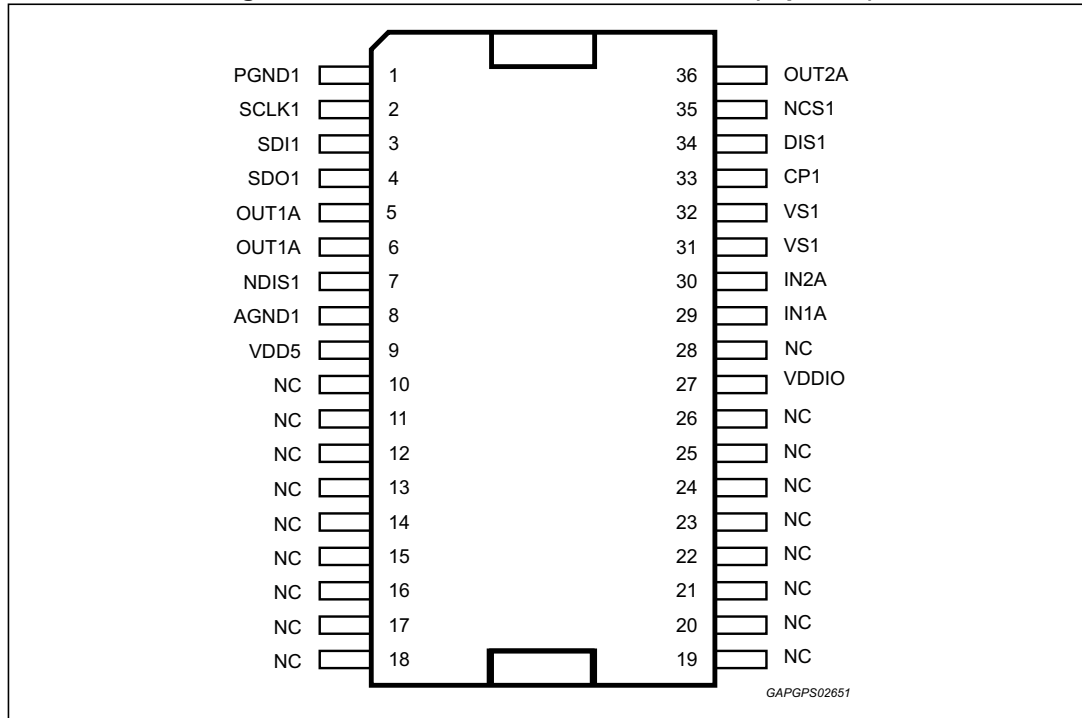


Figure 3. Pin connection of L9960T version (top view)

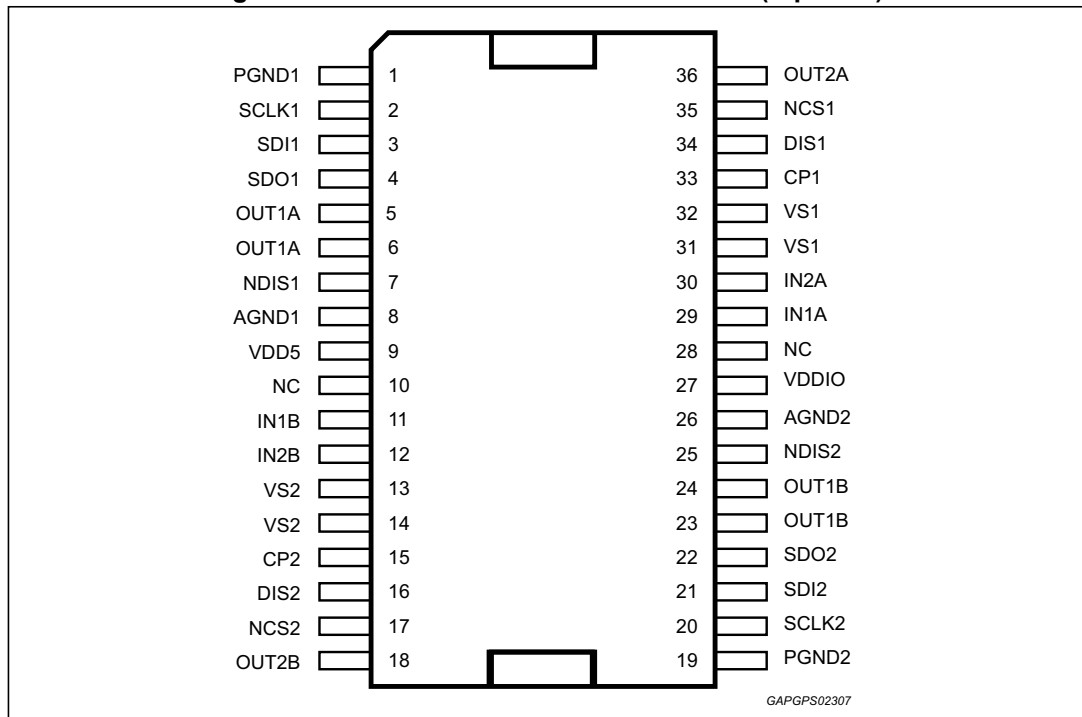


Table 2. Pin definition (PSSO36twin die) and function

Pin #	Pin name	Function	I/O Type
1	PGND1	Power Ground	GND
2	SCLK1	SPI Serial Clock Input (internal pull-down)	I
3	SDI1	SPI Data In Input (internal pull-down)	I
4	SDO1	SPI Serial Data Out. Tri-state output buffer, Transfers data to the μ C	O
5	OUT1A	Output of DMOS half bridge 1 [device A]	O
6			
7	NDIS1	Bidirectional Enable pin: open drain output pulled low in case of VDD over/under voltage. If the input is pulled low OUT 1-2 go to tri-state.	I/O
8	AGND1	Analog Ground pin	GND
9	VDD5	Regulated 5V supply	I
10	NC	Not connected pin	
11 ⁽¹⁾	IN1B	Input Half Bridge 1 (internal pull-down) [device B]. Acting as PWM at power-up, can be configured to IN1 via SPI frame	I
12 ⁽¹⁾	IN2B	Input Half Bridge 2 (internal pull-down) [device B]. Acting as DIR at power-up, can be configured as IN2 via SPI frame.	I
13 ⁽¹⁾	VS2	Power supply voltage for Power Stages (external reverse protection required)	I
14 ⁽¹⁾			
15 ⁽¹⁾	CP2	Tank capacitor for Charge Pump output	O
16 ⁽¹⁾	DIS2	Disable pin: if it is pulled high Out1-2 are in tri-state (internal pull-up)	I
17 ⁽¹⁾	NCS2	SPI Chip Select Input (internal pull-up)	I
18 ⁽¹⁾	OUT2B	Output of DMOS half bridge 2 [device B]	O
19 ⁽¹⁾	PGND2	Power Ground	GND
20 ⁽¹⁾	SCLK2	SPI Serial Clock Input (internal pull-down)	I
21 ⁽¹⁾	SDI2	SPI Data In Input (internal pull-down).	I
22 ⁽¹⁾	SDO2	SPI Serial Data Out	O
23 ⁽¹⁾	OUT1B	Output of DMOS half bridge 1 [device B]. multi-bonding	O
24 ⁽¹⁾			
25 ⁽¹⁾	NDIS2	Bidirectional Enable pin: open drain output pulled low in case of VDD over/under voltage. If the input is pulled low OUT 1-2 go to tri-state.	I/O
26 ⁽¹⁾	AGND2	Analog Ground pin	GND
27	VDDIO	Regulated 3.3/5V supply for SDO output buffer	I
28	NC	Not connected pin	-
29	IN1A	Input Half Bridge 1 (internal pull-down) [device A]. Acting as PWM at power-up, can be configured to IN1 via SPI	I
30	IN2A	Input Half Bridge 2 (internal pull-down) [device A]. Acting as DIR at power-up, can be configured as IN2 via SPI.	I

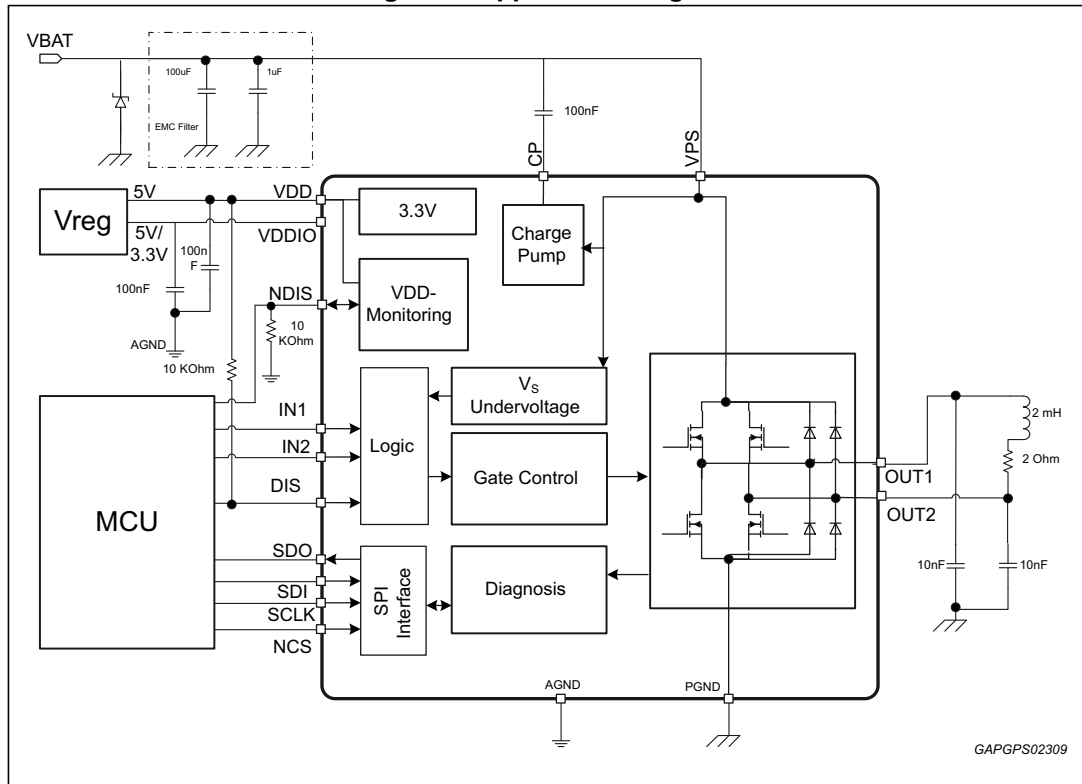
Table 2. Pin definition (PSSO36twin die) and function (continued)

Pin #	Pin name	Function	I/O Type
31	VS1	Power supply voltage for Power Stages (external reverse protection required)	I
32			
33	CP1	Charge Pump output	O
34	DIS1	Disable pin: if it is pulled high Out1-2 are in tri-state (internal pull-up)	I
35	NCS1	SPI Chip Select Input (internal pull-up)	I
36	OUT2A	Output of DMOS half bridge 2 [device A]. multi-bonding	O
EP	AGND1	Exposed Pad connected to PCB Ground	

1. For L9960 version in PSSO36, the pins from 11 to 26 are not connected.

2 Application description

Figure 4. Application diagram



2.1 Functionality

The L9960 is dedicated to be part of an H-Bridge module for automotive applications. The module is used for DC motor driving in applications like ETC, EGR or swirl flap. The L9960 is implemented with a microcontroller, an input filter (fulfillment of the EMC/EMI requirements) and an over-voltage protection diode (optional).

2.2 Example of application circuit

Figure 5. Application schematic (example)

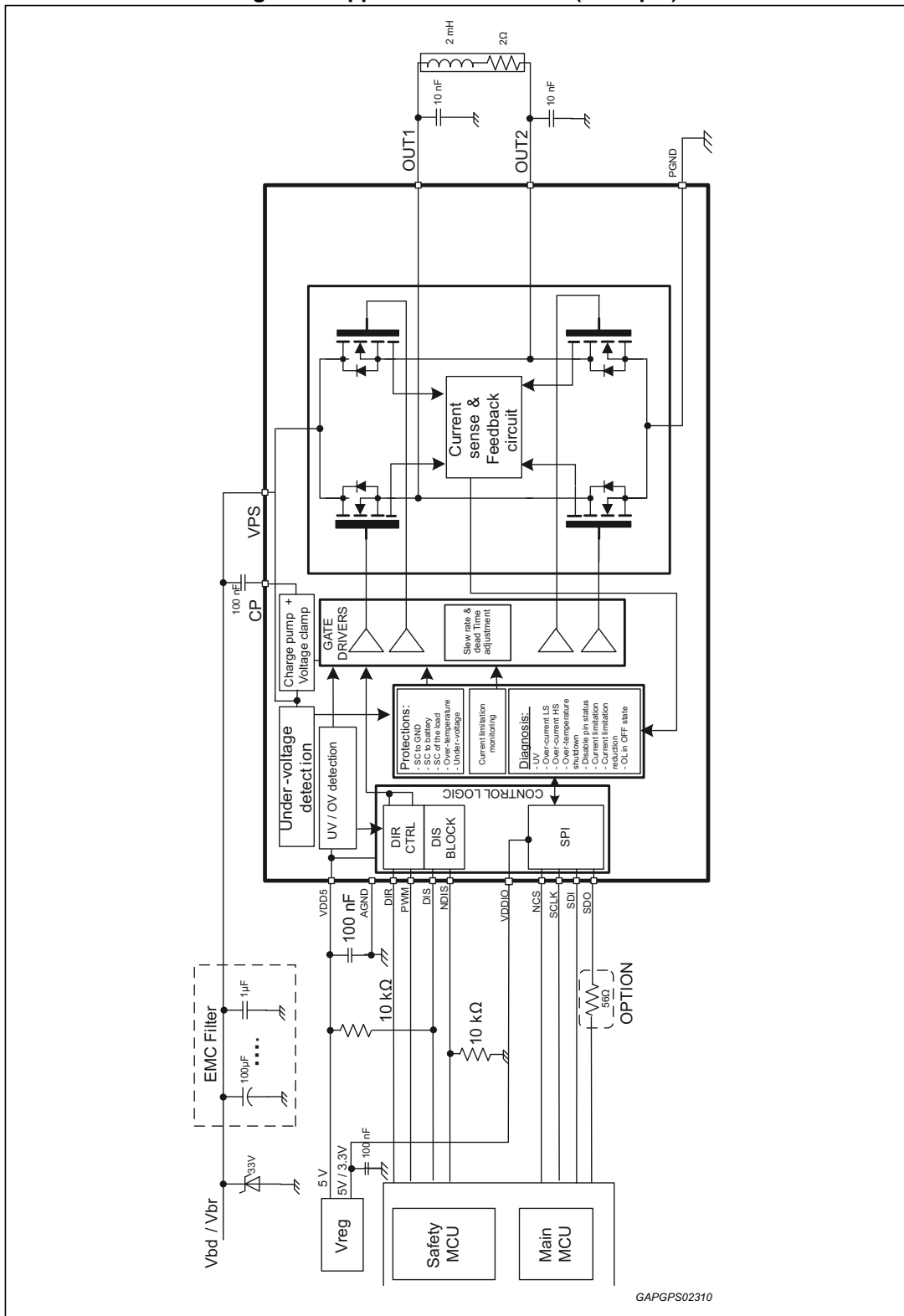
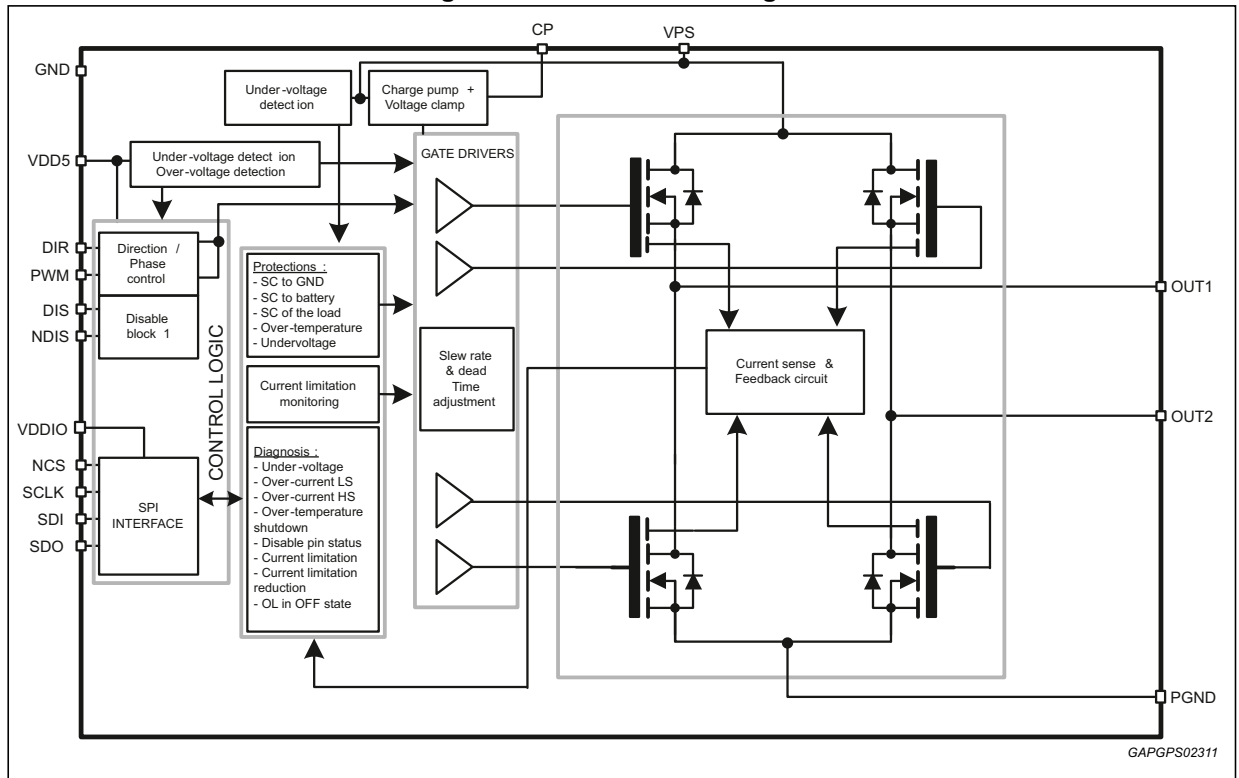


Figure 6. Detailed block diagram



3 General electrical characteristics

3.1 Absolute maximum ratings

Warning: stressing the device above the rating listed in the “Absolute maximum ratings” table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to the absolute maximum ratings conditions for extended periods may affect the device reliability. Refer also to the STMicroelectronics SURE program and other relevant quality document.

Table 3. Absolute maximum ratings

Symbol	Parameter	Condition	Min	Max	Unit
V _{ps}	Supply voltage	Continuous	-1	40	V
V _{out1,2}	Output voltage	Continuous. OUT is limited by VPS	-1	40	V
VDD5	Logic supply voltage	0 V < Vps < 40 V	-0.3	19	V
VDDIO	SDO supply voltage	0V<Vps<40V	-0.3	19	V
VCP	VCP output voltage	-	-0.3	Vps+5	V
V _{IN}	Logic input voltage (NCS, SDI, SCLK, DIR, PWM, DIS, NDIS)	0 V < Vps < 40 V	-0.3	19	V
V _o	Logic output voltage (SDO, NDIS)	0 V < VDD5 < 19 V	-0.3	19	V
-	Human body model ESD compliance for pins: OUTx,VPS (not tested at ATE) ⁽¹⁾	HBM (100 pF/1.5 kohm)	-4	4	kV
-	Human body model ESD compliance for other pins than OUTx, VPS (not tested at ATE)	HBM (100 pF/1.5 kohm)	-2	2	kV
-	Charge Device Model ESD compliance for all pins (not tested at ATE)	CDM; according Q100-011 classification C3B	-750 -500	750 ⁽²⁾ 500 ⁽³⁾	V V
-	ISO 7637 pulses	Cf. standards	-	-	-
-	Latch-up immunity	According to JEDEC 78 class 2 level A			

- 1. Versus GND.
- 2. Corner pins.
- 3. All pins.

Note: Test circuit according HBM (EIA/JESD22-A114-B) and CDM (EIA/JESD22-C101-C).

4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com.

ECOPACK[®] is an ST trademark.

4.1 PowerSSO-36 (exposed pad) package mechanical data

Figure 7. PowerSSO-36 (exposed pad) package mechanical drawing

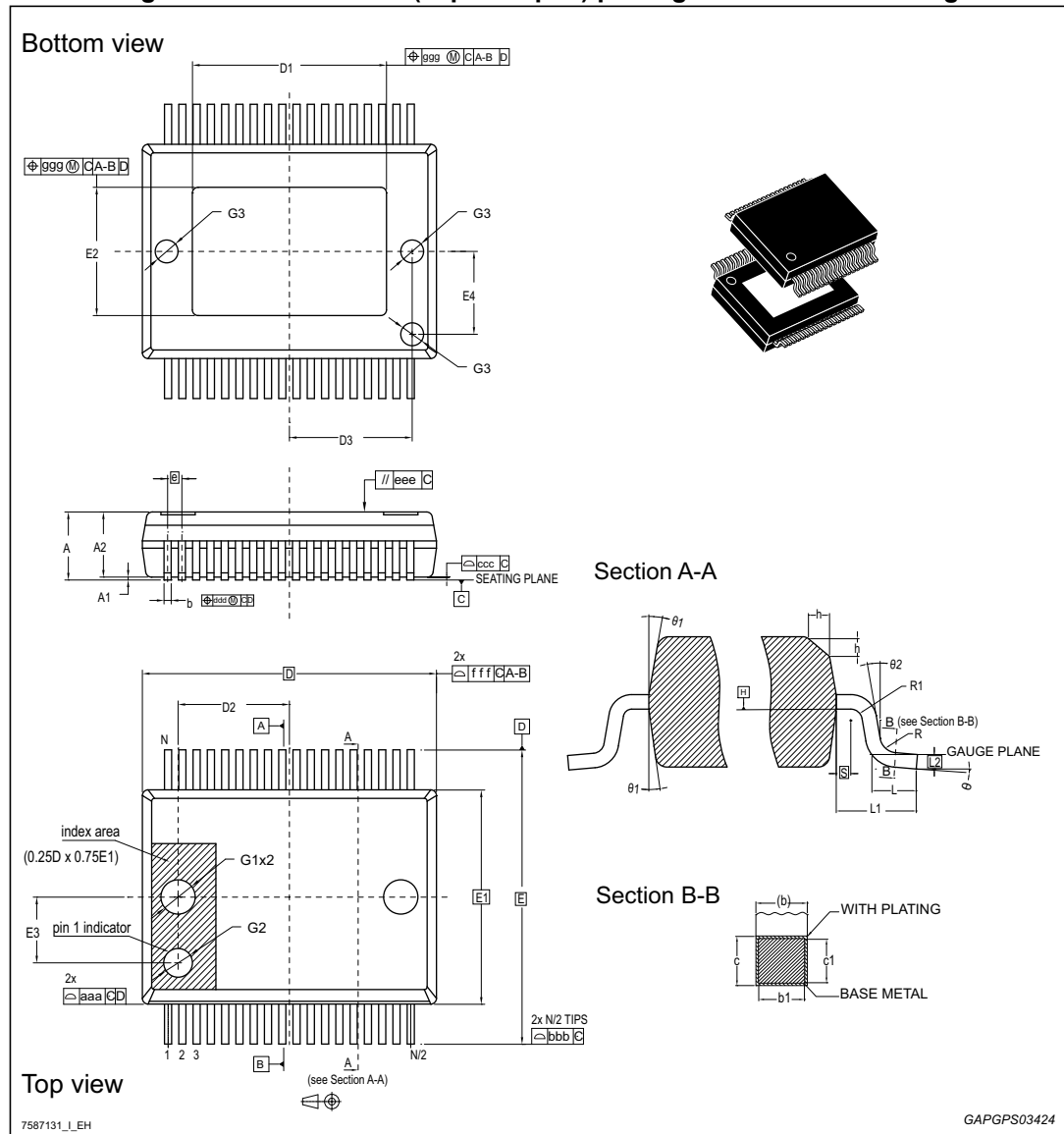


Table 4. PowerSSO-36 (exposed pad) package mechanical data

Ref	Dimensions					
	Millimeters			Inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
Θ	0°	-	8°	0°	-	8°
Θ1	5°	-	10°	5°	-	10°
Θ2	0°	-	-	0°	-	-
A	2.15	-	2.45	0.0846	-	0.0965
A1	0.0	-	0.1	0.0	-	0.0039
A2	2.15	-	2.35	0.0846	-	0.0925
b	0.18	-	0.32	0.0071	-	0.0126
b1	0.13	0.25	0.3	0.0051	0.0098	0.0118
c	0.23	-	0.32	0.0091	-	0.0126
c1	0.2	0.2	0.3	0.0079	0.0079	0.0118
D ⁽²⁾	10.30 BSC			0.4055 BSC		
D1	VARIATION					
D2	-	3.65	-	-	0.1437	-
D3	-	4.3	-	-	0.1693	-
e	0.50 BSC			0.0197 BSC		
E	10.30 BSC			0.4055 BSC		
E1 ⁽²⁾	7.50 BSC			0.2953 BSC		
E2	VARIATION					
E3	-	2.3	-	-	0.0906	-
E4	-	2.9	-	-	0.1142	-
G1	-	1.2	-	-	0.0472	-
G2	-	1	-	-	0.0394	-
G3	-	0.8	-	-	0.0315	-
h	0.3	-	0.4	0.0118	-	0.0157
L	0.55	0.7	0.85	0.0217	-	0.0335
L1	1.40 REF			0.0551 REF		
L2	0.25 BSC			0.0098 BSC		
N	36			1.4173		
R	0.3	-	-	0.0118	-	-
R1	0.2	-	-	0.0079	-	-
S	0.25	-	-	0.0098	-	-

Table 4. PowerSSO-36 (exposed pad) package mechanical data (continued)

Ref	Dimensions					
	Millimeters			Inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
Tolerance of form and position						
aaa	0.2			0.0079		
bbb	0.2			0.0079		
ccc	0.1			0.0039		
ddd	0.2			0.0079		
eee	0.1			0.0039		
fff	0.2			0.0079		
ggg	0.15			0.0059		
VARIATIONS						
Option A						
D1	6.5	-	7.1	0.2559	-	0.2795
E2	4.1	-	4.7	0.1614	-	0.1850
Option B						
D1	4.9	-	5.5	0.1929	-	0.2165
E2	4.1	-	4.7	0.1614	-	0.1850
Option C						
D1	6.9	-	7.5	0.2717	-	0.2953
E2	4.3	-	5.2	0.1693	-	0.2047

1. Values in inches are converted from mm and rounded to 4 decimal digits.
2. Dimensions D and E1 do not include mold flash or protrusions. Allowable mold flash or protrusions is '0.25 mm' per side D and '0.15 mm' per side E1. D and E1 are Maximum plastic body size dimensions including mold mismatch.

5 Revision history

Table 5. Document revision history

Date	Revision	Changes
04-Dec-2015	1	Initial release.

IMPORTANT NOTICE – PLEASE READ CAREFULLY

STMicroelectronics NV and its subsidiaries (“ST”) reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST’s terms and conditions of sale in place at the time of order acknowledgement.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of Purchasers’ products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2015 STMicroelectronics – All rights reserved